## Contents

Prelace		V
Chapter 1	<ul> <li>General Points of View on Electrical Properties</li> <li>Materials</li> </ul>	s of 1
1-1	Introduction	
1-2	Crystalline Covalent Solids	
1-3	Crystalline Ionic Solids	
1-4	Crystalline Metallic Solids	
1-5	Noncrystalline Solids	
1-6	Electron Motion in Metallic and Covalent Crystals	
1-7	Magnetic Phenomena	
1-8	Electric Polarization Phenomena	
1-9	Lattice Motion	
Chapter 2	— The Wave Nature of Particles	16
2-1	Introduction	
2-2	A Classical Preliminary to Wave Functions	
2-3	A Second Classical Preliminary to Wave Functions	
2-4	The Wave Nature of Particles	41/3

viii	CONTENTS
------	----------

2-5 2-6 2-7 2-8 2-9 2-10	The Schrödinger Wave Equation Average Values of Observable Quantities Boundary Conditions on the Wave Equation The Rectangular Potential Well—An Example Identical Particles Spin	
2-11	Comments on Actually Solving the Wave Equation	
57529 (3020)	<ul> <li>Electron States in Crystalline Solids</li> </ul>	48
3-1	The Independent Electron Model	
3-2	Electron States in a Rectangular Solid	
3-3	The Mapping of Electron States—Density of States	
3-4	The Electron States in a One-Dimensional Crystal—The Kronig-Penney Model	
3-5	Electron States in a One-Dimensional Crystal—Fourier Analysis	
3-6	Density of States with Band Structure	
Chapter 4 -	– Charge Carrier Densities	76
4-1	The Fermi-Dirac Probability Function	
4-2	Electrons in a Uniform Rectangular Potential Well- Fermi Energy	
4-3	State Occupancy in the Band Structure Model— Pure Ideal Crystals	
4-4	Semiconductor State Occupancy and Fermi Energy with Impurities	
Chapter 5 -	– Charge Carrier Dynamics	103
5-1	Homogeneous Electron-State Occupancy Transients—Relaxation Time and Lifetime	
5-2	The Concept of Effective Mass	
5-3	Current Flow in Terms of Energy Band Location	
5-4	Macroscopic Electron and Hole Flow Equations	
Chapter 6 -	<ul> <li>Bulk and Surface Effects — Simple Junctions</li> </ul>	137
<b>-</b> 44 245 344	Resistivity	
6-2	The Haynes-Shockley Experiment	
6-3	The Hall Effect	
6-4	The p-n Semiconductor Junction	
6-5	The Biased p-n Semiconductor Junction	
6-6	High-Level Injection and Avalanche Breakdown in p-n Junctions	
6-7	Metal-Semiconductor Junctions	
6-8	Semiconductor-Insulator Surfaces—MIS Structure	

Chapter 7	— Bipolar and Field-Effect Transistors	181
7-1	The Bipolar Transistor in Active-Mode Bias	
7-2	The Bipolar Transistor in Saturation-Mode Bias	
7-3	The Bipolar Transistor in Cutoff-Mode Bias	
7-4	Switching Transients	
7-5	High-Frequency, Small-Signal Operation	
7-6	MIS Field-Effect Transistor Characteristics	
Chapter 8	— Electric Polarization Phenomena and Dielectric	
	Properties	220
8-1	The Macroscopic Polarization Field;	
	Dielectric Constant	
8-2	Electronic Polarizability	
8-3	Ionic Polarization	
8-4	Orientational Polarization	
8-5	Polarizability and the Dielectric Constant—Internal Fields	
8-6	Crystal Lattice Vibrations and Piezoelectricity	
8-7	Other Areas of Interest in Dielectric Properties	
Chapter 9	— Magnetic Fields and "Nonmagnetic" Materials	257
9-1	Free-Space Magnetostatics	
9-2	Magnetic Dipole Moment Density—The Magneti-	
9-3	zation Vector	
3-3	Curl M as an Equivalent Current Density—	
9-4	Amperian Currents	
	Magnetic Field Intensity and Scalar Magnetic Potential	
9-5	An Alternate Point of View—Magnetic Charges	
9-6	Classical Diamagnetism	
9-7	Force, Torque, and Energy for a Magnetic Dipole Moment	
9-8	Spin Paramagnetism in Nontransition Metals	
9-9	Paramagnetism from Localized Atomic Magnetic	
	Dipoles	
Chapter 1	.0 — Magnetic Order in Technical Magnetic Materials	285
10-1		<del></del>
10-2		
10-2		
10-3	Energy	

## X CONTENTS

10-4

10-5

10-6	Domains and Domain Walls	
10-7	Magnetization Curves of Picture-Frame Silicon- Iron Crystals	
10-8	Gyromagnetic Effects in Nonconducting Magnetic Materials	
Bibliography		323
Index		325

Magnetic Anisotropy and Magnetostriction

Magnetization Curves of a Small Magnetic Particle